

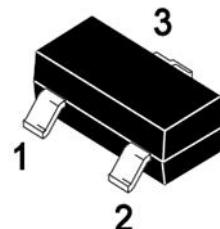
SSCN123GS6

NPN Type Digital Transistor (built-in resistors)

➤ Features

| VCC | VIN | IO | R1 | R2/R1 Typ. |
|-----|---------|-------|-------|------------|
| 50V | -5~+12V | 100mA | 2.2kΩ | 21 |

➤ Pin configuration



SOT-23

➤ Description

Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).

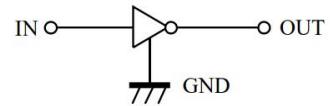
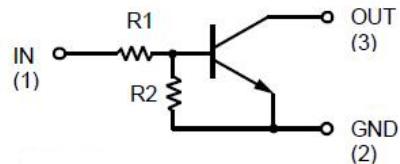
The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects. Only the on/off conditions need to be set for operation, making the device design easy.

➤ Applications

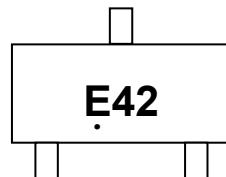
- Amplifying signal
- Electronic switch
- Oscillating circuit
- Variable resistance

➤ Ordering Information

| Device | Package | Shipping |
|------------|---------|-----------|
| SSCN123GS6 | SOT-23 | 3000/Reel |



Circuit Diagram



Marking (Top View)

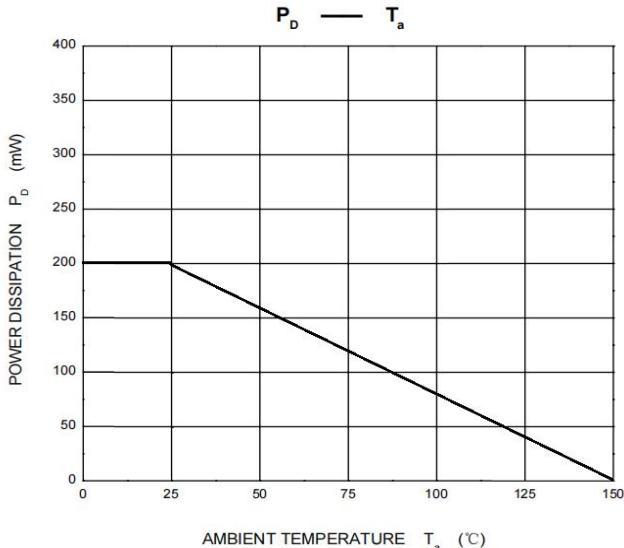
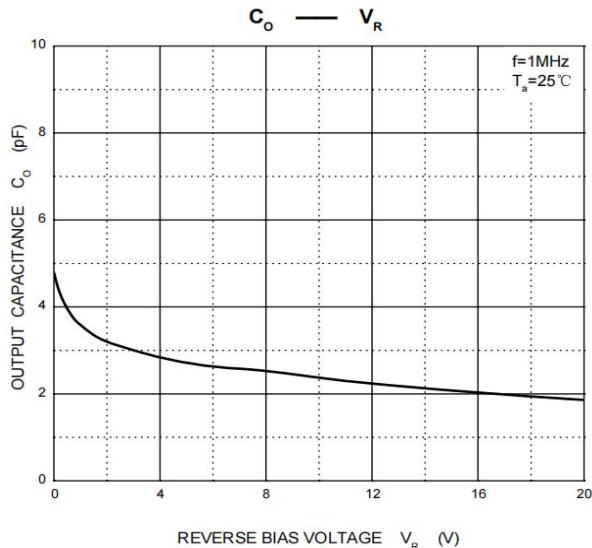
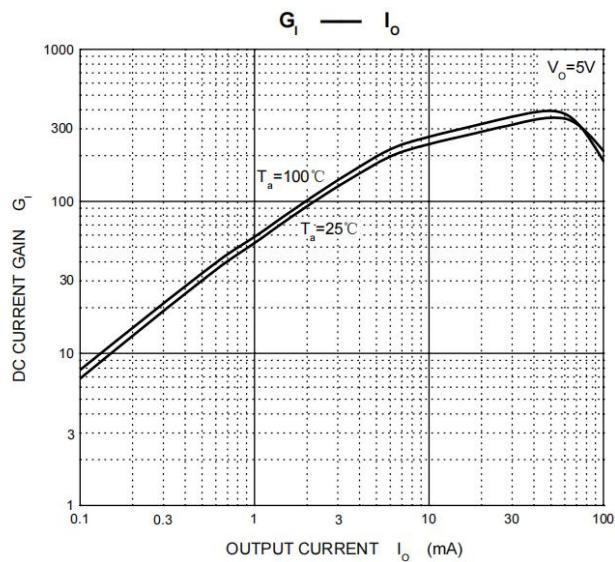
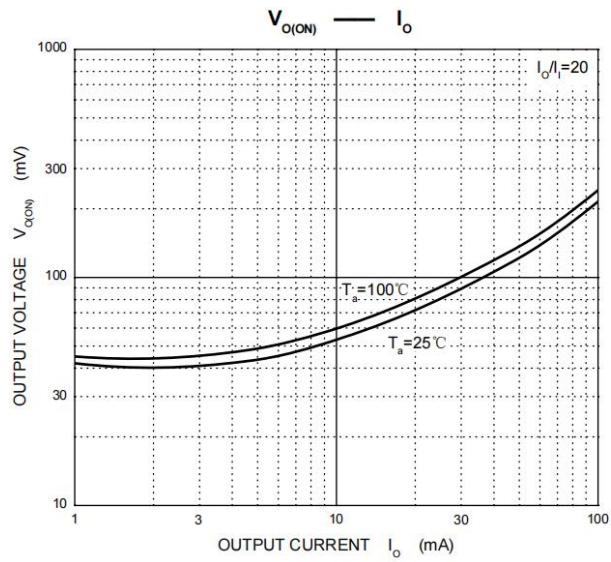
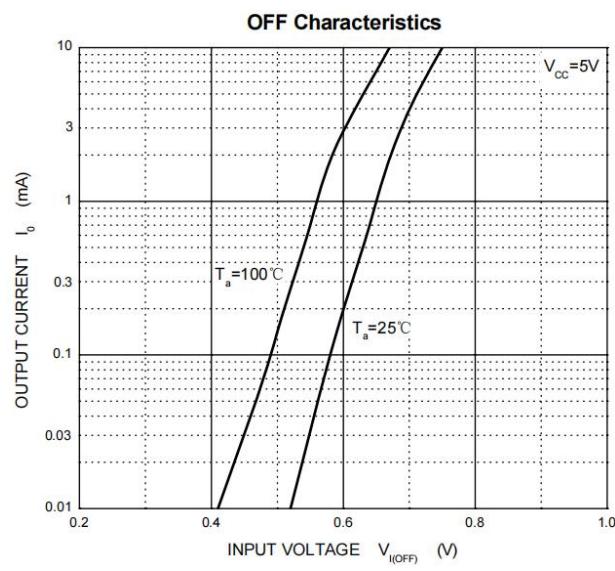
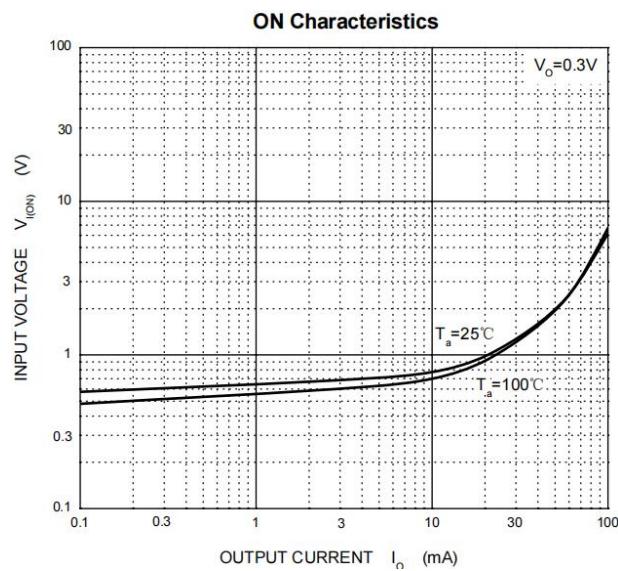
➤ Absolute Maximum Ratings($T_A=25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Value | Unit |
|----------------------|-----------|------------|------|
| Supply Voltage | V_{CC} | 50 | V |
| Input Voltage | V_{IN} | -5 to +12 | V |
| Output current | I_O | 100 | mA |
| Power Dissipation | P_D | 200 | mW |
| Junction Temperature | T_J | -55 to 150 | °C |
| Storage Temperature | T_{STG} | -55 to 150 | °C |

➤ Electrical Characteristics ($T_A=25^\circ C$ unless otherwise noted)

| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
|----------------------|--------------|------------------------------------|------|------|------|------|
| Input Voltage | $V_{I(off)}$ | $V_{CC} = 5V, I_O = 0.1mA$ | 0.5 | | | V |
| | $V_{I(on)}$ | $V_{CC} = 0.3V, I_O = 5mA$ | | | 1.1 | V |
| Output Voltage | $V_{O(on)}$ | $I_O/I_I = 5mA/0.25mA$ | | 0.1 | 0.3 | V |
| Input Current | I_I | $V_I = 5V$ | | | 3.6 | mA |
| Output Current | $I_O(off)$ | $V_{CC} = 50V, V_I = 0V$ | | | 0.5 | uA |
| DC Current Gain | G_1 | $V_O = 5V, I_O = 10mA$ | 80 | | | |
| Input Resistance | R_I | | 1.54 | 2.2 | 2.86 | KΩ |
| Resistance Ration | R_2/R_1 | | 17 | 21 | 26 | |
| Transition Frequency | f_T | $V_O = 10V, I_O = 5mA, f = 100MHz$ | | 250 | | MHz |

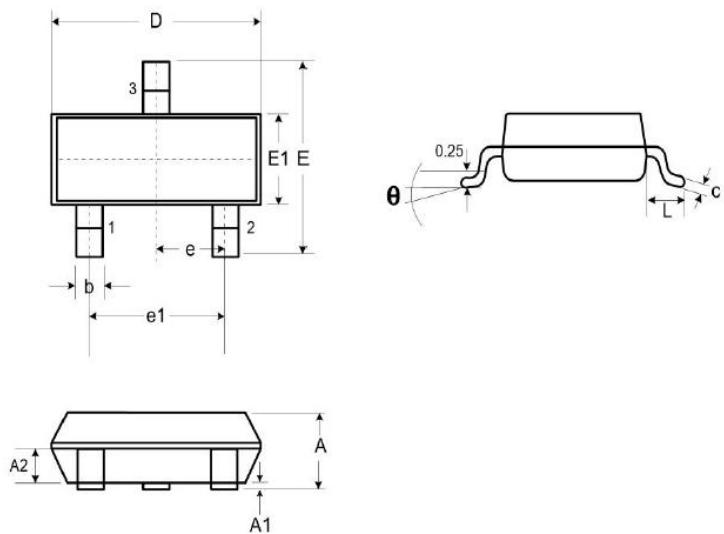
➤ Typical Performance Characteristics ($T_a=25^\circ\text{C}$ unless otherwise noted)



➤ Package Information

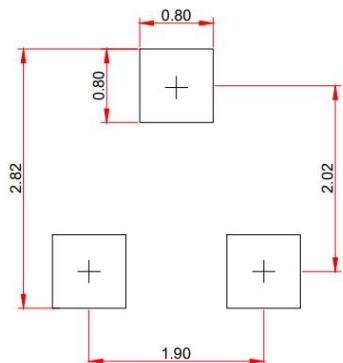
● Mechanical Data

SOT-23



| DIM | Millimeters | | |
|-----------|-------------|------|------|
| | Min. | Typ. | Max. |
| A | 0.89 | - | 1.12 |
| A1 | 0.01 | - | 0.10 |
| A2 | 0.88 | 0.95 | 1.02 |
| b | 0.30 | - | 0.51 |
| c | 0.08 | - | 0.18 |
| D | 2.80 | 2.90 | 3.04 |
| E | 2.10 | 2.37 | 2.64 |
| E1 | 1.20 | 1.30 | 1.40 |
| e | 0.95 | | |
| e1 | 1.90 | | |
| L | 0.40 | 0.50 | 0.60 |
| L1 | 0.55 | | |
| N | 3 | | |
| θ | 0° | - | 8° |

● Recommended Pad outline



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